

Sample & $\frac{1}{2}$ Buy

Reference Design

INA250A1, INA250A2, INA250A3, INA250A4

ZHCSDO5B –APRIL 2015–REVISED DECEMBER 2015

INA250 集成有精密分流电阻的 **36V** 低侧**/**高侧双向零漂移分流监视器

1 特性

- 精密的集成分流电阻:
	- 分流电阻:2mΩ
	- 分流电阻容差:0.1%(最大值)
	- 15A 持续电流(–40°C 至 85°C)
	- 0°C 至 125°C 温度系数: 10ppm/°C
- 高精度:
	- 增益误差(分流和放大器):0.3%(最大值)
	- 偏移电流:50mA(最大值,INA250A2)
- 四种增益可供选择:
	- INA250A1:200mV/A
	- INA250A2:500mV/A
	- INA250A3:800mV/A
	- INA250A4:2V/A
- 宽共模电压范围:-0.1V 至 36V
- 特定工作温度范围: -40°C 至 125°C

2 应用

- 测试设备
- 电源
- 服务器
- 电信设备
- 汽车用
- 太阳能逆变器
- 电源管理

3 说明

INA250 是电压输出、电流感测放大器系列,其集成了 一个内部分流电阻,能够在 0V 至 36V 共模电压范围 上实现高精度电流测量,并且与电源电压无关。该器件 是一款双向、低侧/高侧分流监视器,可使用外部参考 来测量双向流入内部电流感测电阻传感器的电流。集成 的精密电流感测电阻可使器件获得校准级别的测量精度 以及超低温漂,并确保始终可实施针对感测电阻而优化 的 Kelvin 布局。

INA250 系列提供四级输出电压:200mV/A、

500mV/A、800mV/A 和 2V/A。该器件已经过完全测 试,可在 125℃ 最高温度下提供高达 10A 的持续电 流。INA250 由一个 2.7V 至 36V 的单电源供电, 最大 供电电流为 300μA。INA250 的所有增益版本均在扩展 工作温度范围(-40℃至 +125℃)内额定运行, 并且 采用薄型小外形尺寸 (TSSOP)-16 封装。

器件信息**(1)**

器件型号	封装	封装尺寸 (标称值)
INA250A1	TSSOP (16)	5.00mm x 4.40mm
INA250A2		
INA250A3		
INA250A4		

(1) 如需了解所有可用封装,请见数据表末尾的可订购产品附录。

简化电路原理图

INA250A1, INA250A2, INA250A3, INA250A4

ZHCSDO5B –APRIL 2015–REVISED DECEMBER 2015 **www.ti.com.cn**

目录

4 修订历史记录

Changes from Revision A (May 2015) to Revision B Page

Changes from Original (April 2015) to Revision A Page

5 Pin Configuration and Functions

Pin Functions

ZHCSDO5B –APRIL 2015–REVISED DECEMBER 2015 **www.ti.com.cn**

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

(1) Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.

6.2 ESD Ratings

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

6.4 Thermal Information

(1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, SPRA953.

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6.5 Electrical Characteristics

At $T_A = 25^{\circ}$ C, VS = 5 V, V_{IN+} = 12 V, V_{REF} = 2.5 V, I_{SENSE} = IN+ = 0 A, unless otherwise noted.

(1) $RTI = referred-to-input.$
(2) The supply voltage range

The supply voltage range maximum is 36 V, but the reference voltage cannot be higher than 18 V.

(3) See the *Integrated Shunt Resistor* section for additional information regarding the integrated current-sensing resistor.

(4) The internal shunt resistor is intended to be used with the internal amplifier and is not intended to be used as a stand-alone resistor. See the *Integrated Shunt Resistor* section for more information.

(5) See Figure 30 and the *Layout* section for additional information on the current derating and layout recommendations to improve the current handling capability of the device at higher temperatures.

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TRUMENTS

XAS

Electrical Characteristics (continued)

At $T_A = 25^{\circ}$ C, VS = 5 V, V_{IN+} = 12 V, V_{REF} = 2.5 V, I_{SENSE} = IN+ = 0 A, unless otherwise noted.

(6) System gain error includes amplifier gain error and the integrated sense resistor tolerance. System gain error does not include the stress related characteristics of the integrated sense resistor. These characteristics are described in the *Shunt Resistor* section of the *Electrical Characteristics* table.

(7) See *Typical Characteristics* curve, *Output Voltage Swing vs Output Current* (Figure 19).

6.6 Typical Characteristics

At $T_A = 25^{\circ}$ C, VS = 5 V, V_{IN+} = 12 V, V_{REF} = 2.5 V, I_{SENSE} = IN+ = 0 A, unless otherwise noted.

INA250A1, INA250A2, INA250A3, INA250A4

ZHCSDO5B –APRIL 2015–REVISED DECEMBER 2015 **www.ti.com.cn**

Typical Characteristics (continued)

Typical Characteristics (continued)

ZHCSDO5B –APRIL 2015–REVISED DECEMBER 2015 **www.ti.com.cn**

Typical Characteristics (continued)

At $T_A = 25^{\circ}$ C, VS = 5 V, V_{IN+} = 12 V, V_{REF} = 2.5 V, I_{SENSE} = IN+ = 0 A, unless otherwise noted.

Typical Characteristics (continued)

7 Detailed Description

7.1 Overview

The INA250 features a 2-mΩ, precision, current-sensing resistor and a 36-V common-mode, zero-drift topology, precision, current-sensing amplifier integrated into a single package. High precision measurements are enabled through the matching of the shunt resistor value and the current-sensing amplifier gain providing a highlyaccurate, system-calibrated solution. Multiple gain versions are available to allow for the optimization of the desired full-scale output voltage based on the target current range expected in the application.

7.2 Functional Block Diagram

7.3 Feature Description

7.3.1 Integrated Shunt Resistor

The INA250 features a precise, low-drift, current-sensing resistor to allow for precision measurements over the entire specified temperature range of –40°C to 125°C. The integrated current-sensing resistor ensures measurement stability over temperature as well as improving layout and board constraint difficulties common in high precision measurements.

The onboard current-sensing resistor is designed as a 4-wire (or Kelvin) connected resistor that enables accurate measurements through a force-sense connection. Connecting the amplifier inputs pins (VIN– and VIN+) to the sense pins of the shunt resistor (SH– and SH+) eliminates many of the parasitic impedances commonly found in typical very-low sensing-resistor level measurements. Although the sense connection of the current-sensing resistor can be accessed via the SH+ and SH– pins, this resistor is not intended to be used as a stand-alone component. The INA250 is system-calibrated to ensure that the current-sensing resistor and current-sensing amplifier are both precisely matched to one another. Use of the shunt resistor without the onboard amplifier results in a current-sensing resistor tolerance of approximately 5%. To achieve the optimized system gain specification, the onboard sensing resistor must be used with the internal current-sensing amplifier.

Feature Description (continued)

The INA250 has approximately 4.5 m Ω of package resistance. 2 m Ω of this total package resistance is a precisely-controlled resistance from the Kelvin-connected current-sensing resistor used by the amplifier. The power dissipation requirements of the system and package are based on the total 4.5-mΩ package resistance between the IN+ and IN– pins. The heat dissipated across the package when current flows through the device ultimately determines the maximum current that can be safely handled by the package. The current consumption of the silicon is relatively low, leaving the total package resistance carrying the high load current as the primary contributor to the total power dissipation of the package. The maximum safe-operating current level is set to ensure that the heat dissipated across the package is limited so that no damage to the resistor or the package itself occurs or that the internal junction temperature of the silicon does not exceed a 150°C limit.

External factors (such as ambient temperature, external air flow, and PCB layout) can contribute to how effectively the heat developed as a result of the current flowing through the total package resistance can be removed from within the device. Under the conditions of no air flow, a maximum ambient temperature of 85°C, and 1-oz. copper input power planes, the INA250 can accommodate continuous current levels up to 15 A. As shown in Figure 30, the current handling capability is derated at temperatures above the 85°C level with safe operation up to 10 A at a 125°C ambient temperature. With air flow and larger 2-oz. copper input power planes, the INA250 can safely accommodate continuous current levels up to 15 A over the entire –40°C to 125°C temperature range.

Figure 30. Maximum Current vs Temperature

7.3.2 Short-Circuit Duration

The INA250 features a physical shunt resistance that is able to withstand current levels higher than the continuous handling limit of 15 A without sustaining damage to the current-sensing resistor or the current-sensing amplifier if the excursions are very brief. Figure 31 shows the short-circuit duration curve for the INA250.

Figure 31. Short-Circuit Duration

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Feature Description (continued)

7.3.3 Temperature Stability

System calibration is common for many industrial applications to eliminate initial component and system-level errors that can be present. A system-level calibration can reduce the initial accuracy requirement for many of the individual components because the errors associated with these components are effectively eliminated through the calibration procedure. Performing this calibration can enable precision measurements at the temperature in which the system is calibrated, but as the system temperature changes as a result of external ambient changes or due to self heating, measurement errors are reintroduced. Without accurate temperature compensation used in addition to the initial adjustment, the calibration procedure is not effective in accounting for these temperatureinduced changes. One of the primary benefits of the very low temperature coefficient of the INA250 (including both the integrated current-sensing resistor and current-sensing amplifier) is ensuring that the device measurement remains highly accurate, even when the temperature changes throughout the specified temperature range of the device.

For the integrated current-sensing resistor, the drift performance is shown in Figure 32. Although several temperature ranges are specified in the *Electrical Characteristics* table, applications operating in ranges other than those described can use Figure 32 to determine how much variance in the shunt resistor value can be expected. As with any resistive element, the tolerance of the component varies when exposed to different temperature conditions. For the current-sensing resistor integrated in the INA250, the resistor does vary slightly more when operated in temperatures ranging from –40°C to 0°C than when operated from 0°C to 125°C. However, even in the -40° C to 0°C temperature range, the drift is still quite low at 25 ppm/°C.

Figure 32. Sensing Resistor vs Temperature

An additional aspect to consider is that when current flows through the current-sensing resistor, power is dissipated across this component. This dissipated power results in an increase in the internal temperature of the package, including the integrated sensing resistor. This resistor self-heating effect results in an increase of the resistor temperature helping to move the component out of the colder, wider drift temperature region.

7.4 Device Functional Modes

7.4.1 Amplifier Operation

The INA250 current-sense amplifier can be configured to measure both unidirectional and bidirectional currents through the reference voltage level applied to the reference pin, REF. The reference voltage connected to REF sets the output level that corresponds with a zero input current condition. For unidirectional operation, tie the REF pin to ground so that when the current increases, the output signal also increases upwards from this reference voltage (or ground in this case). For bidirectional currents, an external voltage source can be used as the reference voltage connected to the REF pin to bias up the output. Set the reference voltage to enable sufficient range above and below this level based on the expected current range to be measured. Positive currents result in an output signal that increases from the zero-current output level set by the reference voltage whereas negative currents result in an output signal that decreases.

For both unidirectional and bidirectional applications, the amplifier transfer function is shown in Equation 1:

 $V_{OUT} = (I_{LOAD} \times GAM) + V_{REF}$

where:

- I_{LOAD} is the current being measured passing through the internal shunt resistor,
- GAIN is the corresponding gain (mA/V) of the selected device, and
- V_{REF} is the voltage applied to the REF pin (1) (1)

As with any difference amplifier, the INA250 common-mode rejection ratio is affected by any impedance present at the REF input. This concern is not a problem when the REF pin is connected directly to a reference or power supply. When using resistive dividers from a power supply or a reference voltage, buffer the REF pin with an op amp.

7.4.2 Input Filtering

An obvious and straightforward location for filtering is at the device output; however, this location negates the advantage of the low output impedance of the output stage buffer. The input then represents the best location for implementing external filtering. Figure 33 shows the typical implementation of the input filter for the device.

Figure 33. Input Filter

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Device Functional Modes (continued)

The addition of external series resistance at the input pins to the amplifier, however, creates an additional error in the measurement. Keep the value of these series resistors to 10 Ω or less, if possible, to reduce the affect to accuracy. The internal bias network illustrated in Figure 33 present at the input pins creates a mismatch in input bias currents when a differential voltage is applied between the input pins, as shown in Figure 34.

Figure 34. Input Bias Current vs Differential Input Voltage

7.4.2.1 Calculating Gain Error Resulting from External Filter Resistance

If additional external series filter resistors are added to the circuit, the mismatch in bias currents results in a mismatch of voltage drops across the filter resistors. This mismatch creates a differential error voltage that subtracts from the voltage developed across the Kelvin connection of the shunt resistor, thus reducing the voltage that reaches the amplifier input terminals. Without the additional series resistance, the mismatch in input bias currents has little effect on device operation as a result of the low input bias current of the amplifier and the typically low impedance of the traces between the shunt and amplifier input pins. The amount of error these external filter resistors add to the measurement can be calculated using Equation 3, where the gain error factor is calculated using Equation 2.

The amount of variance between the differential voltage present at the device input relative to the voltage developed at the shunt resistor is based both on the external series resistance value as well as the internal input resistors, R_{INT} ; see Figure 33. The reduction of the shunt voltage reaching the device input pins appears as a gain error when comparing the output voltage relative to the voltage across the shunt resistor. A factor can be calculated to determine the amount of gain error that is introduced by the addition of external series resistance. Equation 2 calculates the expected deviation from the shunt voltage compared to the expected voltage at the device input pins.

$$
Gain Error Factor = \frac{(1250 \times R_{INT})}{(1250 \times R_{S}) + (1250 \times R_{INT}) + (R_{S} \times R_{INT})}
$$

where:

- R_{INT} is the internal input resistor and
- R_S is the external series resistance (2)

Gain Error (%) = $100 - (100 \times$ Gain Error Factor)

With the adjustment factor equation including the device internal input resistance, this factor varies with each gain version; see Table 1. Each individual device gain error factor is listed in Table 2.

The gain error that can be expected from the addition of the external series resistors can then be calculated based on Equation 3.

(3)

Device Functional Modes (continued)

Table 1. Input Resistance

Table 2. Device Gain Error Factor

For example, using an INA250A2 and the corresponding gain error equation from Table 2, a series resistance of 10 Ω results in a gain error factor of 0.991. The corresponding gain error is then calculated using Equation 3, resulting in a gain error of approximately 0.84% because of the external 10-Ω series resistors.

7.4.3 Shutting Down the Device

Although the device does not have a shutdown pin, the low power consumption allows for the device to be powered from the output of a logic gate or transistor switch that can turn on and turn off the voltage connected to the device power-supply pin. However, in current-shunt monitoring applications, there is also a concern for how much current is drained from the shunt circuit in shutdown conditions. Evaluating this current drain involves considering the device simplified schematic in shutdown mode, as shown in Figure 35.

Note that there is typically an approximate 1-MΩ impedance (from the combination of the feedback and input resistors) from each device input to the REF pin. The amount of current flowing through these pins depends on the respective configuration. For example, if the REF pin is grounded, calculating the effect of the 1-M Ω impedance from the shunt to ground is straightforward. However, if the reference or op amp is powered when the device is shut down, the calculation is direct. Instead of assuming 1 MΩ to ground, assume 1 MΩ to the reference voltage. If the reference or op amp is also shut down, some knowledge of the reference or op amp output impedance under shutdown conditions is required. For instance, if the reference source functions similar to an open circuit when un-powered, little or no current flows through the 1-MΩ path.

7.4.4 Using the Device with Common-Mode Transients Above 36 V

With a small amount of additional circuitry, the device can be used in circuits subject to transients higher than 36 V (such as in automotive applications). Use only zener diodes or zener-type transient absorbers (sometimes referred to as *transzorbs*); any other type of transient absorber has an unacceptable time delay. Start by adding a pair of resistors, as shown in Figure 36, as a working impedance for the zener. Keeping these resistors as small as possible is preferable, most often approximately 10 Ω. This value limits the affect on accuracy with the addition of these external components, as described in the *Input Filtering* section. Device interconnections between the shunt resistor and amplifier have a current handling limit of 1 A. Using a 10-Ω resistor limits the allowable transient range to 10 V above the zener clamp in order to not damage the device. Larger resistor values can be used in this protection circuit to accommodate a larger transient voltage range, resulting in a larger affect on gain error. Because this circuit limits only short-term transients, many applications are satisfied with a 10-Ω resistor along with conventional zener diodes of the lowest power rating available.

Figure 36. Device Transient Protection

8 Applications and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

The INA250 measures the voltage developed across the internal current-sensing resistor when current passes through it. The ability to drive the reference pin to adjust the functionality of the output signal offers multiple configurations, as discussed in this section.

8.2 Typical Applications

8.2.1 Current Summing

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Typical Applications (continued)

8.2.1.1 Design Requirements

Three daisy-chained devices are illustrated in Figure 37. The reference input of the first INA250 sets the quiescent level on the output of all the INA250 devices in the string.

8.2.1.2 Detailed Design Procedure

The outputs of multiple INA250 devices are easily summed by connecting the output signal of one INA250 to the reference input of a second INA250. Summing beyond two devices is possible by repeating this configuration, connecting the output signal of the next INA250 to the reference pin of a subsequent INA250 in the chain. The output signal of the final INA250 in this chain includes the current level information for all channels in the chain.

8.2.1.3 Application Curve

Figure 38. Daisy-Chain Configuration Output Response

Typical Applications (continued)

8.2.2 Parallel Multiple INA250 Devices for Higher Current

Figure 39. Parallel Summing Configuration

8.2.2.1 Design Requirements

The parallel connection for multiple INA250 devices can be used to reduce the equivalent overall sense resistance, enabling monitoring of higher current levels than a single device is able to accommodate alone. This configuration also uses a summing arrangement, as described in the *Current Summing* section. A parallel summing configuration is shown in Figure 39.

8.2.2.2 Detailed Design Procedure

With a summing configuration the output of the first channel is fed into the reference input of the second, adding the distributed measurements back together into a single measured value.

8.2.2.3 Application Curve

 $VS = 24 V, V_{REF} = 12 V$

Figure 40. Parallel Configuration Output Response

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Typical Applications (continued)

8.2.3 Current Differencing

Figure 41. Current Differencing Configuration

Typical Applications (continued)

8.2.3.1 Design Requirements

Occasionally, the need may arise to confirm that the current into a load is identical to the current coming out of a load, such as when performing diagnostic testing or fault detection. This procedure requires precision current differencing. This method is the same as current summing, except that the two amplifiers have the respective inputs connected opposite of each other. Under normal operating conditions, the final output is very close to the reference value and proportional to any current difference. Figure 41 is an example of two INA250 devices connected for current differencing.

8.2.3.2 Detailed Design Procedure

The load current can also be measured directly at the output of the first channel. Although technically this configuration is current differencing, this connection (see Figure 41) is really intended to allow the upper (positive) sense channel to report any positive-going excursions in the overall output and the lower (negative) sense channel to report any negative-going excursions.

8.2.3.3 Application Curve

 $VS = 5 V, V_{REF} = 2.5 V$

Figure 42. Current Differencing Configuration Output Response

9 Power Supply Recommendations

The input circuitry of the device can accurately measure signals on common-mode voltages beyond the powersupply voltage, VS. For example, the voltage applied to the VS power-supply pin can be 5 V, whereas the load power-supply voltage being monitored (the common-mode voltage) can be as high as 36 V. Note also that the device can withstand the full 0-V to 36-V range at the input pins, regardless of whether the device has power applied or not. Power-supply bypass capacitors are required for stability and must be placed as closely as possible to the supply and ground pins of the device. A typical value for this supply bypass capacitor is 0.1 μF. Applications with noisy or high-impedance power supplies can require additional decoupling capacitors to reject power-supply noise.

10 Layout

10.1 Layout Guidelines

- The INA250 is specified for current handling of up to 10 A over the entire -40°C to 125°C temperature range using a 1-oz. copper pour for the input power plane as well as no external airflow passing over the device.
- The primary current-handling limitation for the INA250 is how much heat is dissipated inside the package. Efforts to improve heat transfer out of the package and into the surrounding environment improve the ability of the device to handle currents of up to 15 A over the entire –40°C to 125°C temperature range.
- Heat transfer improvements primarily involve larger copper power traces and planes with increased copper thickness (2 oz.) as well as providing airflow to pass over the device. The INA250EVM features a 2-oz. copper pour for the planes and is capable of supporting 15 A at temperatures up to 125°C.
- Place the power-supply bypass capacitor as close as possible to the supply and ground pins. The recommended value of this bypass capacitor is 0.1 µF. Additional decoupling capacitance can be added to compensate for noisy or high-impedance power supplies.

10.2 Layout Examples

Figure 43. Recommended Layout

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Layout Examples (continued)

Figure 44. Recommended Layout Schematic

11 器件和文档支持

11.1 文档支持

11.1.1 相关文档

《INA250EVM 用户指南》, SBOU153

11.2 相关链接

下面的表格列出了快速访问链接。范围包括技术文档、支持与社区资源、工具和软件,以及样片或购买的快速访 问。

表 **3.** 相关链接

11.3 社区资源

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

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Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

11.4 商标

E2E is a trademark of Texas Instruments. All other trademarks are the property of their respective owners.

11.5 静电放电警告

ESD 可能会损坏该集成电路。德州仪器 (TI) 建议通过适当的预防措施处理所有集成电路。如果不遵守正确的处理措施和安装程序 , 可 能会损坏集成电路。

<u>【《</u>▲ ESD 的损坏小至导致微小的性能降级,大至整个器件故障。 精密的集成电路可能更容易受到损坏,这是因为非常细微的参数更改都可 能会导致器件与其发布的规格不相符。

11.6 Glossary

SLYZ022 — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

12 机械、封装和可订购信息

以下页中包括机械、封装和可订购信息。这些信息是针对指定器件可提供的最新数据。这些数据会在无通知且不对 本文档进行修订的情况下发生改变。欲获得该数据表的浏览器版本,请查阅左侧的导航栏。

PACKAGING INFORMATION

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

PACKAGE OPTION ADDENDUM

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⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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TEXAS

TAPE AND REEL INFORMATION

STRUMENTS

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

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PACKAGE MATERIALS INFORMATION

*All dimensions are nominal

TEXAS NSTRUMENTS

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TUBE

B - Alignment groove width

*All dimensions are nominal

PACKAGE OUTLINE

PW0016A TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE

NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.

EXAMPLE BOARD LAYOUT

PW0016A TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

PW0016A TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE

NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.

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